



SOT-23 Plastic-Encapsulate MOSFETS

P-Channel 30-V(D-S) MOSFET

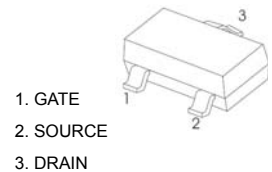
FEATURE

TrenchFET Power MOSFET

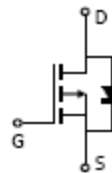
APPLICATIONS

- Load Switch for Portable Devices
- DC/DC Converter
- **Pb-Free package is available**
RoHS product for packing code suffix "G"
Halogen free product for packing code suffix "H"

SOT-23



MARKING: S3



Maximum ratings ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current	I_D	-1.9	A
Continuous Source-Drain Diode Current	I_S	-0.83	
Maximum Power Dissipation	P_D	0.35	W
Thermal Resistance from Junction to Ambient($t \leq 5s$)	$R_{\theta JA}$	357	$^{\circ}\text{C/W}$
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-50 ~+150	



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Electrical characteristics (T_a=25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Static						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =-250μA	-30			V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-1		-3	
Gate-Source Leakage	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V			-1	μA
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} =-10V, I _D =-1.9A		0.158	0.190	Ω
		V _{GS} =-4.5V, I _D =-1.4A		0.275	0.330	
Forward Transconductance ^a	g _{fs}	V _{DS} =-5V, I _D =-1.9A	1			S
Dynamic ^b						
Input Capacitance	C _{iss}	V _{DS} =-15V,V _{GS} =0V,f =1MHz		155		pF
Output Capacitance	C _{oss}			35		
Reverse Transfer Capacitance	C _{rss}			25		
Total Gate Charge	Q _g	V _{DS} =-15V,V _{GS} =-10V,I _D =-1.9A		4	8	nC
		V _{DS} =-15V,V _{GS} =-4.5V,I _D =-1.9A		2	4	
Gate-Source Charge	Q _{gs}			0.6		
Gate-Drain Charge	Q _{gd}			1		
Gate Resistance	R _g	f =1MHz	1.7	8.5	17	Ω
Turn-On Delay Time	t _{d(on)}	V _{DD} =-15V, R _L =10Ω, I _D =-1.5A, V _{GEN} =-10V,R _g =1Ω		4	8	ns
Rise Time	t _r			11	18	
Turn-Off Delay Time	t _{d(off)}			11	18	
Fall Time	t _f			8	16	
Turn-On Delay Time	t _{d(on)}	V _{DD} =-15V, R _L =10Ω, I _D =-1.5A, V _{GEN} =-4.5V,R _g =1Ω		36	44	
Rise Time	t _r			37	45	
Turn-Off Delay Time	t _{d(off)}			12	18	
Fall Time	t _f			9	14	
Drain-source Body diode characteristics						
Continuous Source-Drain Diode Current	I _S	T _C =25°C			-1.75	A
Pulse Diode Forward Current ^a	I _{SM}				-10	
Body Diode Voltage	V _{SD}	I _S =-1.5A		-0.8	-1.2	V

Notes :

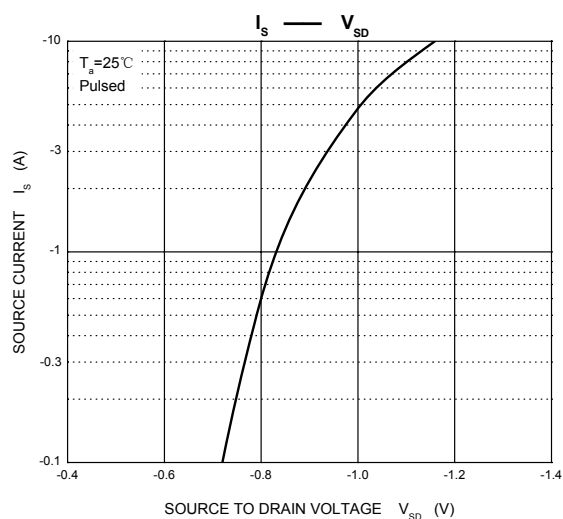
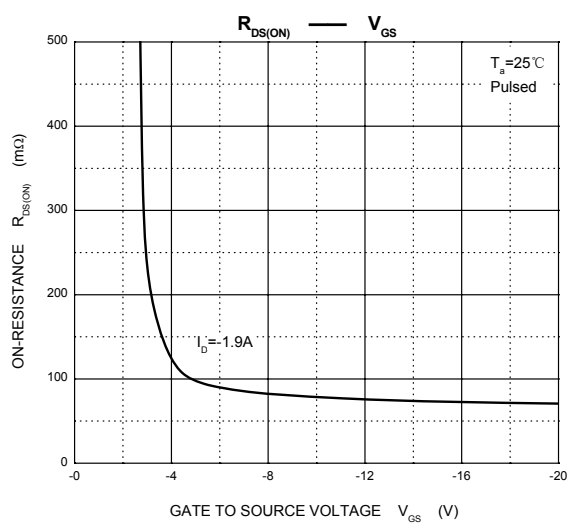
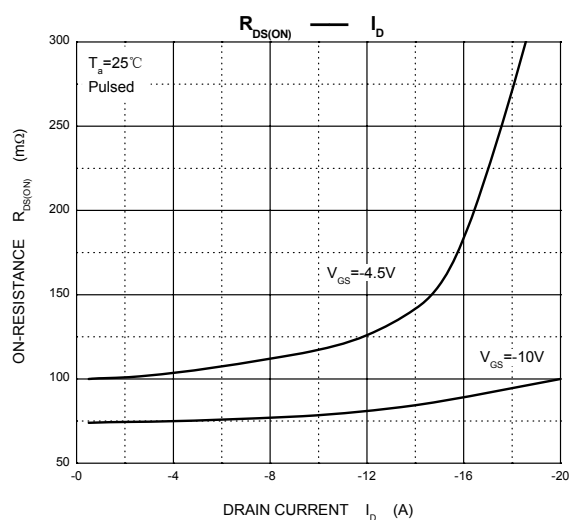
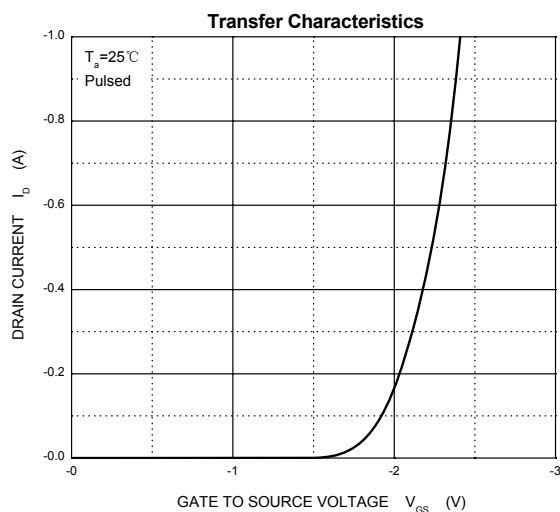
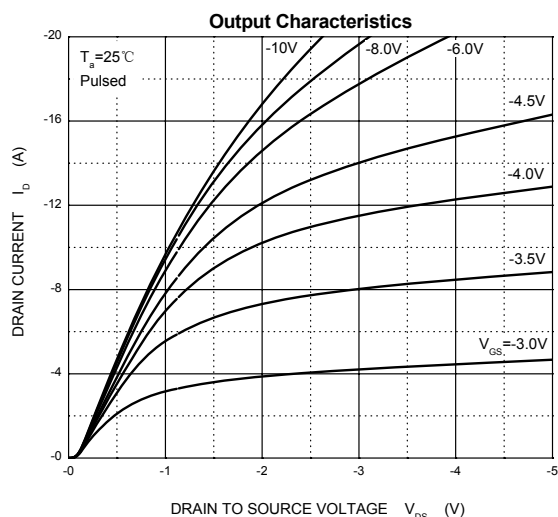
a. Pulse Test : Pulse Width ≤300μs, Duty Cycle ≤2%.

b. Guaranteed by design, not subject to production testing.



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Typical Characteristics

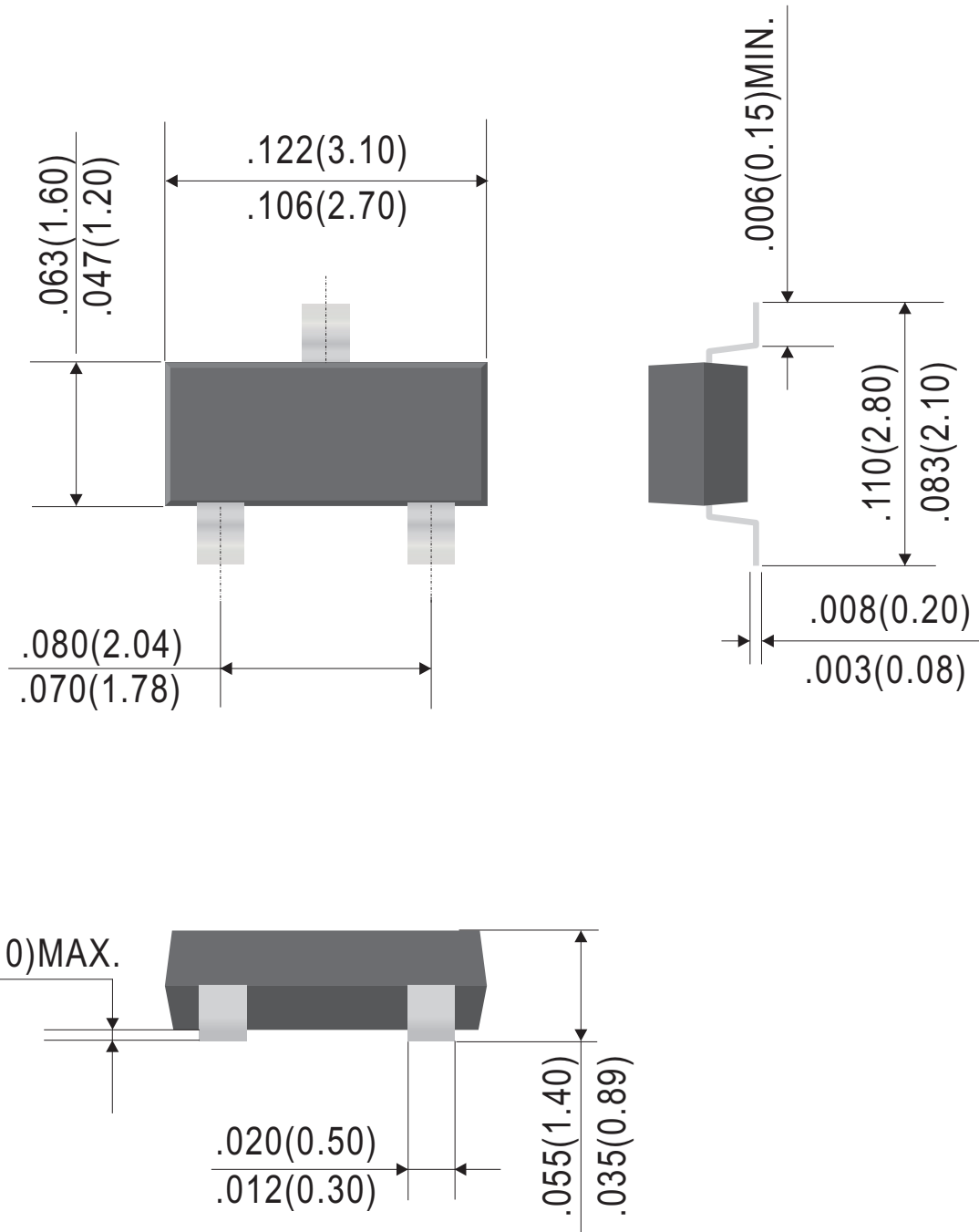




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Outline Drawing

SOT-23



Dimensions in inches and (millimeters)

Rev.D



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Ordering Information:

Device PN	Packing
SE2303-T ⁽¹⁾ G ⁽²⁾ -WS	Tape&Reel: 3 Kpcs/Reel

Note: (1) Packing code, Tape & Reel

(2) RoHS product for packing code suffix "G" ; Halogen free product for packing code suffix "H"

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